





95SQ015 SCHOTTKY RECTIFIER



Features

- 125°C T_J operation (V_R<5V)
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request.

Circuit Diagram



Applications

- Parallel switching power supply
- Converters
- Redundant power subsystems
- · Reverse battery protection

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|--|-----------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | $egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$ | - | 15(DC) 25(Working) | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @T _C =55°C, rectangular wave form | 9 | Α |
| Peak One Cycle Non-Repetitive Surge Current | I _{FSM} | 8.3 ms, half Sine pulse, T _C =25°C | 480 | А |
| Non-Repetitive Avalanche Energy | E _{AS} | T _J =25℃,I _{AS} =1.8A,L=7.4mH | 12 | mJ |
| Repetitive Avalanche Current | I _{AR} | Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. V_A =1.5× V_R typical | 1.8 | А |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|------------------------|-----------------|---|------|--------|-------|
| Forward Voltage Drop* | V _{F1} | @ 9A, Pulse, T _J = 25 °C | 0.31 | 0.34 | V |
| | | @ 18A, Pulse, T _J = 25 °C | 0.35 | 0.37 | v |
| | V_{F2} | @ 9A, Pulse, T _J = 125 °C | 0.22 | 0.25 | V |
| | | @ 18A, Pulse, T _J = 25 °C | 0.28 | 0.31 | V |
| Reverse Current* | I _{R1} | @V _R = rated VR ,T _J = 25 °C | 2 | 7.0 | mA |
| | I _{R2} | @V _R = rated VR ,T _J = 100 °C | 180 | 348 | mA |
| | I _{R3} | @V _R = 12 V ,T _J = 100 °C | 130 | 310 | mA |
| | I _{R4} | @V _R = 5 V ,T _J = 100 °C | 80 | 190 | mA |
| Junction Capacitance | Ст | $@V_R = 5V, T_C = 25 °C, f_{SIG} = 1MHz$ | 1100 | 1300 | pF |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/us |

^{*} Pulse width < 300 µs, duty cycle < 2%

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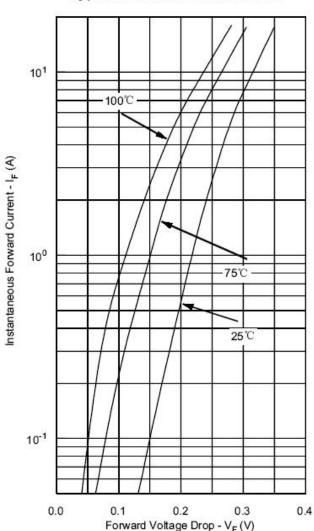


Thermal-Mechanical Specifications:

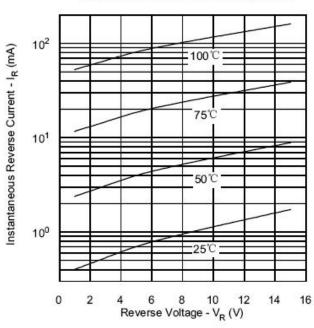
| Characteristics | Symbol | Condition | Specification | Units |
|--|------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +125 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Lead | R _{0JL} | DC operation | 8 | °C/W |
| Typical Thermal Resistance Junction to Ambient | $R_{	heta JA}$ | DC operation | 44 | °C/W |
| Approximate Weight | wt | - | 1.02 | g |

Ratings and Characteristics Curves

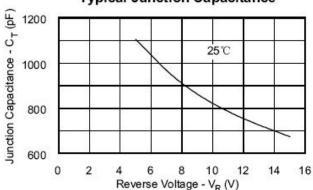
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



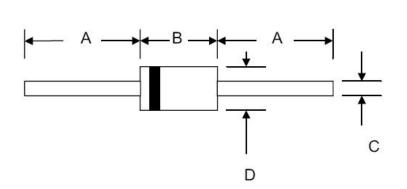
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Mechanical Dimensions DO-201AD



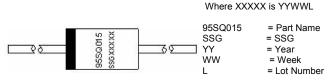
| CVMPOL | Millimeters | | Inches | | |
|--------|-------------|------|--------|-------|--|
| SYMBOL | Min. | Max. | Min. | Max. | |
| А | 25.4 | - | 1.000 | - | |
| В | 8.50 | 9.50 | 0.335 | 0.374 | |
| С | 1.2 | 1.3 | 0.048 | 0.052 | |
| D | 5.0 | 5.6 | 0.197 | 0.220 | |

Ordering Information

| Device | Package | Shipping |
|---------|-----------------------|----------------|
| 95SQ015 | DO-201AD (Pb-Free) | 1250pcs / tape |

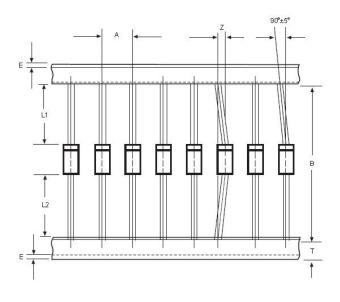
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DO-201AD



| SYMBOL | Millimeters | | |
|---------|-------------|-------|--|
| STWIBOL | Min. | Max. | |
| А | 9.50 | 10.50 | |
| В | 50.9 | 53.9 | |
| Z | - | 1.20 | |
| Т | 5.60 | 6.40 | |
| E | - | 0.80 | |
| IL1-L2I | - | 1.0 | |

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